

# LM148JAN

## Quad 741 Op Amps

### General Description

The LM148 is a true quad LM741. It consists of four independent, high gain, internally compensated, low power operational amplifiers which have been designed to provide functional characteristics identical to those of the familiar LM741 operational amplifier. In addition the total supply current for all four amplifiers is comparable to the supply current of a single LM741 type op amp. Other features include input offset currents and input bias current which are much less than those of a standard LM741. Also, excellent isolation between amplifiers has been achieved by independently biasing each amplifier and using layout techniques which minimize thermal coupling.

The LM148 can be used anywhere multiple LM741 or LM1558 type amplifiers are being used and in applications where amplifier matching or high packing density is required.

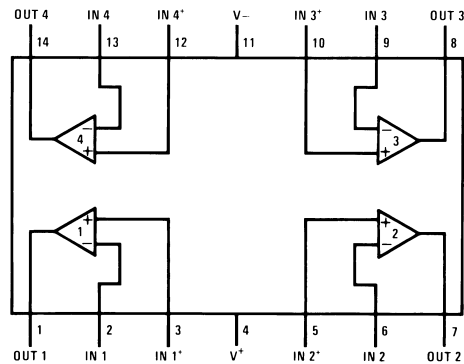
### Features

- 741 op amp operating characteristics
- Class AB output stage—no crossover distortion
- Pin compatible with the LM124
- Overload protection for inputs and outputs
- Low supply current drain: 0.6 mA/Amplifier
- Low input offset voltage: 1 mV
- Low input offset current: 4 nA
- Low input bias current: 30 nA
- High degree of isolation between amplifiers: 120 dB
- Gain bandwidth product (unity gain): 1.0 MHz

### Ordering Information

| NS PART NUMBER | SMD PART NUMBER  | NS PACKAGE NUMBER | PACKAGE DESCRIPTION |
|----------------|------------------|-------------------|---------------------|
| JL148BCA       | JM38510/11001BCA | J14A              | 14LD CERDIP         |
| JL148BDA       | JM38510/11001BDA | W14B              | 14LD CERPACK        |
| JL148BZA       | JM38510/11001BZA | WG14A             | 14LD Ceramic SOIC   |
| JL148SCA       | JM38510/11001SCA | J14A              | 14LD CERDIP         |
| JL148SDA       | JM38510/11001SDA | W14B              | 14LD CERPACK        |

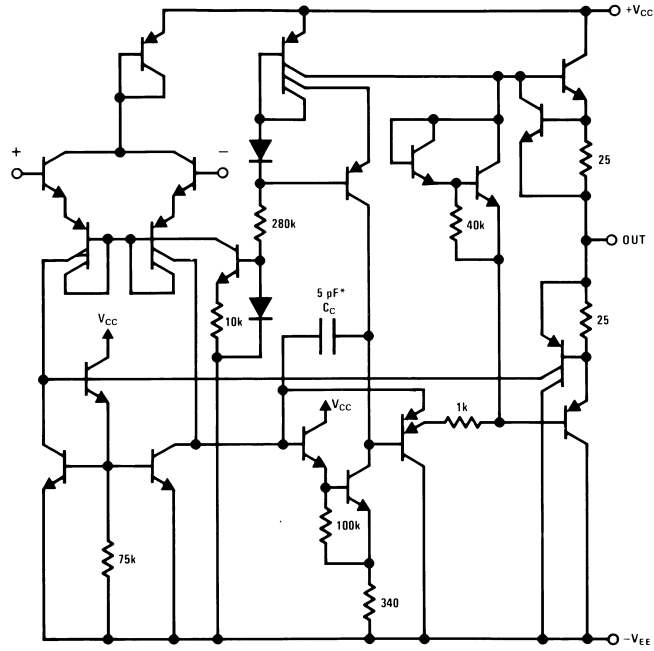
### Connection Diagram



20122702

**Top View**
**See NS Package Number J14A, W14B, WG14A**

# Schematic Diagram



20122701

\* 1 pF in the LM149

## Absolute Maximum Ratings (Note 1)

|   |                        |
|---|------------------------|
| Supply Voltage                                | ±22V                   |
| Input Voltage Range                           | ±20V                   |
| Input Current Range                           | -0.1mA to 10mA         |
| Differential Input Voltage (Note 2)           | ±30V                   |
| Output Short Circuit Duration (Note 3)        | Continuous             |
| Power Dissipation ( $P_d$ at 25°C) (Note 4)   |                        |
| CERDIP  | 400mW                  |
| CERPACK                                       | 350mW                  |
| Thermal Resistance                            |                        |
| $\theta_{JA}$                                 |                        |
| CERDIP (Still Air)                            | 103°C/W                |
| CERDIP (500LF/ Min Air flow)                  | 52°C/W                 |
| CERPACK (Still Air)                           | 140°C/W                |
| CERPACK (500LF/ Min Air flow)                 | 100°C/W                |
| Ceramic SOIC (Still Air)                      | 176°C/W                |
| Ceramic SOIC (500LF/ Min Air flow)            | 116°C/W                |
| $\theta_{JC}$                                 |                        |
| CERDIP  | 19°C/W                 |
| CERPACK                                       | 25°C/W                 |
| Ceramic SOIC                                  | 25°C/W                 |
| Package Weight (typical)                      |                        |
| CERDIP  | TBD                    |
| CERPACK                                       | 465mg                  |
| Ceramic SOIC                                  | 415mg                  |
| Maximum Junction Temperature ( $T_{JMAX}$ )   | 175°C                  |
| Operating Temperature Range                   | -55°C ≤ $T_A$ ≤ +125°C |
| Storage Temperature Range                     | -65°C ≤ $T_A$ ≤ +150°C |
| Lead Temperature (Soldering, 10 sec.) Ceramic | 300°C                  |
| ESD tolerance (Note 5)                        | 500V                   |

## Quality Conformance Inspection

MIL-STD-883, Method 5005 — Group A

| Subgroup | Description         | Temp ( °C) |
|----------|---------------------|------------|
| 1        | Static tests at     | +25        |
| 2        | Static tests at     | +125       |
| 3        | Static tests at     | -55        |
| 4        | Dynamic tests at    | +25        |
| 5        | Dynamic tests at    | +125       |
| 6        | Dynamic tests at    | -55        |
| 7        | Functional tests at | +25        |
| 8A       | Functional tests at | +125       |
| 8B       | Functional tests at | -55        |
| 9        | Switching tests at  | +25        |
| 10       | Switching tests at  | +125       |
| 11       | Switching tests at  | -55        |

## Electrical Characteristics

DC PARAMETERS (The following conditions apply to all parameters, unless otherwise specified.)  $\pm V_{CC} = \pm 20V$ ,  $V_{CM} = 0V$ , measure each amplifier.

| Symbol                        | Parameter                                     | Conditions  | Notes    | Min  | Max  | Units             | Sub-groups |
|-------------------------------|---|---|----------|------|------|-------------------|------------|
| $V_{IO}$                      | Input Offset Voltage                          | $+V_{CC} = 35V, -V_{CC} = -5V,$<br>$V_{CM} = -15V$  |          | -5.0 | +5.0 | mV                | 1          |
|                               |   |   |          | -6.0 | +6.0 | mV                | 2, 3       |
|                               |   | $+V_{CC} = 5V, -V_{CC} = -35V,$<br>$V_{CM} = +15V$  |          | -5.0 | +5.0 | mV                | 1          |
|                               |   |   |          | -6.0 | +6.0 | mV                | 2, 3       |
|                               |   | $+V_{CC} = 5V, -V_{CC} = -5V,$                      |          | -5.0 | +5.0 | mV                | 1          |
|                               |   |   |          | -6.0 | +6.0 | mV                | 2, 3       |
| Delta $V_{IO}$ /<br>Delta $T$ | Input Offset Voltage<br>Temperature Stability | $25^{\circ}C \leq T_A \leq 125^{\circ}C$            | (Note 6) | -25  | 25   | $\mu V/^{\circ}C$ | 2          |
|                               |   | $-55^{\circ}C \leq T_A \leq 25^{\circ}C$            | (Note 6) | -25  | 25   | $\mu V/^{\circ}C$ | 3          |
| $I_{IO}$                      | Input Offset Current                          | $+V_{CC} = 35V, -V_{CC} = -5V,$<br>$V_{CM} = -15V$  |          | -25  | +25  | nA                | 1, 2       |
|                               |   |   |          | -75  | +75  | nA                | 3          |
|                               |   | $+V_{CC} = 5V, -V_{CC} = -35V,$<br>$V_{CM} = +15V$  |          | -25  | +25  | nA                | 1, 2       |
|                               |   |   |          | -75  | +75  | nA                | 3          |
|                               |   | $+V_{CC} = 5V, -V_{CC} = -5V,$                      |          | -25  | +25  | nA                | 1, 2       |
|                               |   |   |          | -75  | +75  | nA                | 3          |
| Delta $I_{IO}$ /<br>Delta $T$ | Input Offset Current<br>Temperature Stability | $25^{\circ}C \leq T_A \leq 125^{\circ}C$            | (Note 6) | -200 | 200  | $pA/^{\circ}C$    | 2          |
|                               |   | $-55^{\circ}C \leq T_A \leq 25^{\circ}C$            | (Note 6) | -400 | 400  | $pA/^{\circ}C$    | 3          |
| $\pm I_{IB}$                  | Input Bias Current                            | $+V_{CC} = 35V, -V_{CC} = -5V,$<br>$V_{CM} = -15V$  |          | -0.1 | 100  | nA                | 1, 2       |
|                               |   |   |          | -0.1 | 325  | nA                | 3          |
|                               |   | $+V_{CC} = 5V, -V_{CC} = -35V,$<br>$V_{CM} = +15V$  |          | -0.1 | 100  | nA                | 1, 2       |
|                               |   |   |          | -0.1 | 325  | nA                | 3          |
|                               |   | $+V_{CC} = 5V, -V_{CC} = -5V,$                      |          | -0.1 | 100  | nA                | 1, 2       |
|                               |   |   |          | -0.1 | 325  | nA                | 3          |
| PSRR+                         | Power Supply Rejection Ratio                  | $-V_{CC} = -20V, +V_{CC} = 20V$ to 10V              | (Note 7) | -100 | 100  | $\mu V/V$         | 1, 2, 3    |
| PSRR-                         | Power Supply Rejection Ratio                  | $+V_{CC} = 20V, -V_{CC} = -20V$ to -10V             | (Note 7) | -100 | 100  | $\mu V/V$         | 1, 2, 3    |
| CMRR                          | Common Mode Rejection Ratio                   | $V_{CM} = \pm 15V, \pm 5V \leq V_{CC} \leq \pm 35V$ |          | 76   |      | dB                | 1, 2, 3    |

## Electrical Characteristics

AC / DC PARAMETERS (The following conditions apply to all parameters, unless otherwise specified.)  
 $\pm V_{CC} = \pm 20V$ ,  $V_{CM} = 0V$ , measure each amplifier.

| Symbol     | Parameter              | Conditions  | Notes | Min | Max | Units | Sub-groups |
|------------|------------------------|---|-------|-----|-----|-------|------------|
| $+ I_{OS}$ | Short Circuit Current  | $+V_{CC} = 15V, -V_{CC} = -15V,$<br>$V_{CM} = -10V$ |       | -55 |     | mA    | 1, 2       |
|            |                        |   |       | -75 |     | mA    | 3          |
| $- I_{OS}$ | Short Circuit Current  | $+V_{CC} = 15V, -V_{CC} = -15V,$<br>$V_{CM} = +10V$ |       |     | 55  | mA    | 1, 2       |
|            |                        |   |       |     | 75  | mA    | 3          |
| $I_{CC}$   | Power Supply Current   | $+V_{CC} = 15V, -V_{CC} = -15V$                     |       |     | 3.6 | mA    | 1          |
|            |                        |   |       |     | 4.5 | mA    | 2, 3       |
| $-A_{VS}$  | Open Loop Voltage Gain | $V_{OUT} = -15V, R_L = 10K\Omega$                   |       | 50  |     | V/mV  | 4          |
|            |                        |   |       | 25  |     | V/mV  | 5, 6       |
|            |                        | $V_{OUT} = -15V, R_L = 2K\Omega$                    |       | 50  |     | V/mV  | 4          |
|            |                        |   |       | 25  |     | V/mV  | 5, 6       |

**Electrical Characteristics** (Continued)

AC / DC PARAMETERS (The following conditions apply to all parameters, unless otherwise specified.)

 $\pm V_{CC} = \pm 20V$ ,  $V_{CM} = 0V$ , measure each amplifier.

| Symbol    | Parameter               | Conditions   | Notes | Min | Max | Units      | Sub-groups |
|-----------|-------------------------|--|-------|-----|-----|------------|------------|
| $+A_{VS}$ | Open Loop Voltage Gain  | $V_{OUT} = +15V$ , $R_L = 10K\Omega$                       |       | 50  |     | V/mV       | 4          |
|           |                         |  |       | 25  |     | V/mV       | 5, 6       |
|           |                         | $V_{OUT} = +15V$ , $R_L = 2K\Omega$                        |       | 50  |     | V/mV       | 4          |
|           |                         |  |       | 25  |     | V/mV       | 5, 6       |
| $A_{VS}$  | Open Loop Voltage Gain  | $V_{CC} = \pm 5V$ , $V_{OUT} = \pm 2V$ , $R_L = 10K\Omega$ |       | 10  |     | V/mV       | 4, 5, 6    |
|           |                         | $V_{CC} = \pm 5V$ , $V_{OUT} = \pm 2V$ , $R_L = 2K\Omega$  |       | 10  |     | V/mV       | 4, 5, 6    |
| $+V_{OP}$ | Output Voltage Swing    | $R_L = 10K\Omega$  |       | +16 |     | V          | 4, 5, 6    |
|           |                         | $R_L = 2K\Omega$   |       | +15 |     | V          | 4, 5, 6    |
| $-V_{OP}$ | Output Voltage Swing    | $R_L = 10K\Omega$  |       |     | -16 | V          | 4, 5, 6    |
|           |                         | $R_L = 2K\Omega$   |       |     | -15 | V          | 4, 5, 6    |
| $TR_{TR}$ | Transient Response Time | $V_{IN} = 50mV$ , $A_V = 1$                                |       |     | 1   | $\mu S$    | 7, 8A, 8B  |
| $TR_{OS}$ | Transient Response Time | $V_{IN} = 50mV$ , $A_V = 1$                                |       |     | 25  | %          | 7, 8A, 8B  |
| $\pm SR$  | Slew Rate               | $V_{IN} = -5V$ to $+5V$ , $A_V = 1$                        |       | 0.2 |     | V/ $\mu S$ | 7, 8A, 8B  |
|           |                         | $V_{IN} = +5V$ to $-5V$ , $A_V = 1$                        |       | 0.2 |     | V/ $\mu S$ | 7, 8A, 8B  |

**Electrical Characteristics**AC PARAMETERS (The following conditions apply to all parameters, unless otherwise specified.)  $\pm V_{CC} = \pm 20V$ ,  $V_{CM} = 0V$ , measure each amplifier.

| Symbol    | Parameter          | Conditions                                    | Notes | Min | Max | Units         | Sub-groups |
|-----------|--------------------|---|-------|-----|-----|---------------|------------|
| $NI_{BB}$ | Noise (Broadband)  | $BW = 10Hz$ to $5KHz$                         |       |     | 15  | $\mu V_{RMS}$ | 7          |
| $NI_{PC}$ | Noise (Popcorn)    | $R_S = 20K\Omega$                             |       |     | 40  | $\mu V_{PK}$  | 7          |
| $C_S$     | Channel Separation | $V_{IN} = \pm 10V$ , A to B, $R_L = 2K\Omega$ |       | 80  |     | dB            | 7          |
|           |                    | $V_{IN} = \pm 10V$ , A to C, $R_L = 2K\Omega$ |       | 80  |     | dB            | 7          |
|           |                    | $V_{IN} = \pm 10V$ , A to D, $R_L = 2K\Omega$ |       | 80  |     | dB            | 7          |
|           |                    | $V_{IN} = \pm 10V$ , B to A, $R_L = 2K\Omega$ |       | 80  |     | dB            | 7          |
|           |                    | $V_{IN} = \pm 10V$ , B to C, $R_L = 2K\Omega$ |       | 80  |     | dB            | 7          |
|           |                    | $V_{IN} = \pm 10V$ , B to D, $R_L = 2K\Omega$ |       | 80  |     | dB            | 7          |
|           |                    | $V_{IN} = \pm 10V$ , C to A, $R_L = 2K\Omega$ |       | 80  |     | dB            | 7          |
|           |                    | $V_{IN} = \pm 10V$ , C to B, $R_L = 2K\Omega$ |       | 80  |     | dB            | 7          |
|           |                    | $V_{IN} = \pm 10V$ , C to D, $R_L = 2K\Omega$ |       | 80  |     | dB            | 7          |
|           |                    | $V_{IN} = \pm 10V$ , D to A, $R_L = 2K\Omega$ |       | 80  |     | dB            | 7          |
|           |                    | $V_{IN} = \pm 10V$ , D to B, $R_L = 2K\Omega$ |       | 80  |     | dB            | 7          |
|           |                    | $V_{IN} = \pm 10V$ , D to C, $R_L = 2K\Omega$ |       | 80  |     | dB            | 7          |

**Electrical Characteristics**DC DRIFT PARAMETERS (The following conditions apply to all parameters, unless otherwise specified.)  $\pm V_{CC} = \pm 20V$ ,  $V_{CM} = 0V$ , measure each amplifier. Delta calculations performed on JAN S and QMLV devices at group B, subgroup 5 only.

| Symbol       | Parameter            | Conditions | Notes | Min | Max | Units | Sub-groups |
|--------------|----------------------|------------|-------|-----|-----|-------|------------|
| $V_{IO}$     | Input Offset Voltage |            |       | -1  | 1   | mV    | 1          |
| $\pm I_{IB}$ | Input Bias Current   |            |       | -15 | 15  | nA    | 1          |

## Electrical Characteristics (Continued)

**Note 1:** Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

**Note 2:** The differential input voltage range shall not exceed the supply voltage range.

**Note 3:** Any of the amplifier outputs can be shorted to ground indefinitely; however, more than one should not be simultaneously shorted as the maximum junction temperature will be exceeded.

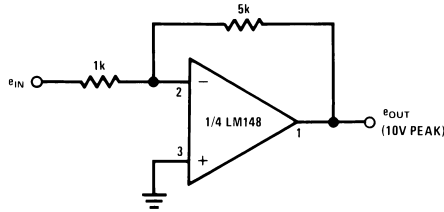
**Note 4:** The maximum power dissipation for these devices must be derated at elevated temperatures and is dictated by  $T_{JMAX}$ ,  $\theta_{JA}$ , and the ambient temperature,  $T_A$ . The maximum available power dissipation at any temperature is  $P_d = (T_{JMAX} - T_A)/\theta_{JA}$  or the number given in the Absolute Maximum Ratings, whichever is less.

**Note 5:** Human body model, 1.5 k $\Omega$  in series with 100 pF.

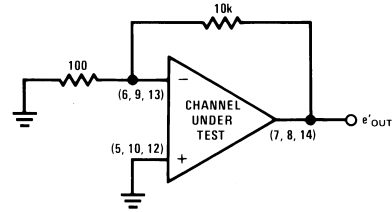
**Note 6:** Calculated parameter.

**Note 7:** Datalogs as  $\mu V$

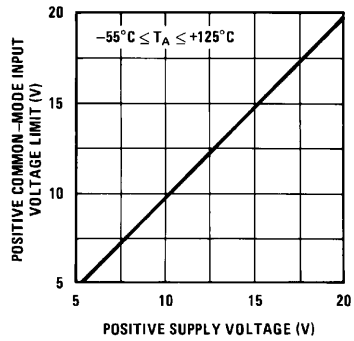
## Cross Talk Test Circuit $V_S = \pm 15V$



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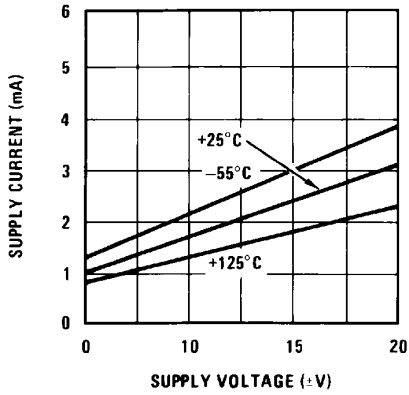
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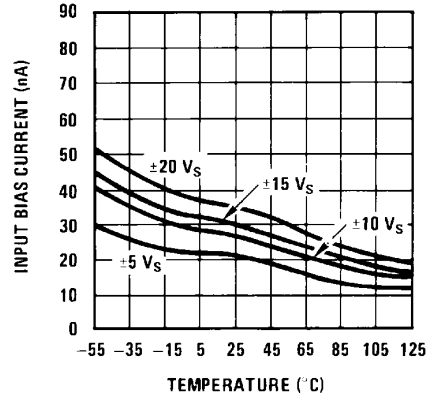
# Typical Performance Characteristics

Supply Current



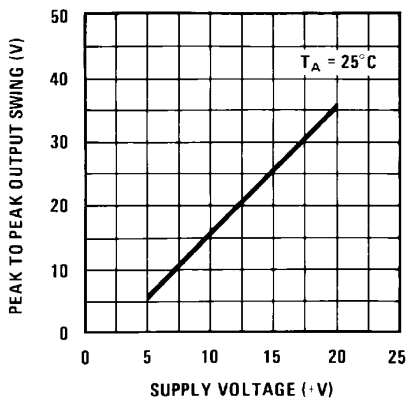
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Input Bias Current



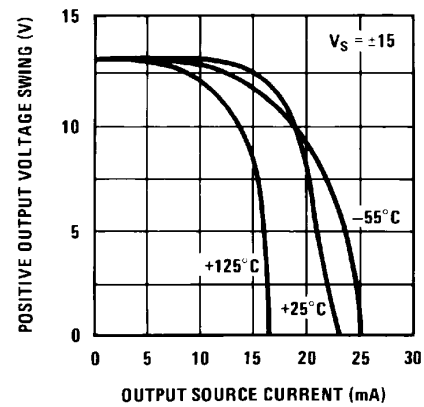
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Voltage Swing



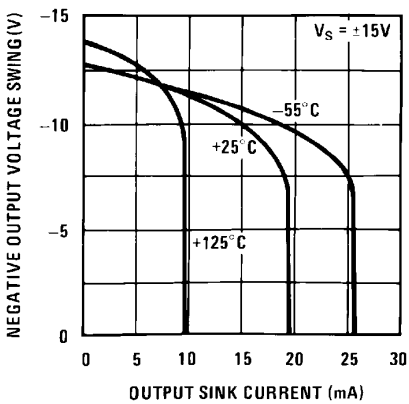
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Positive Current Limit



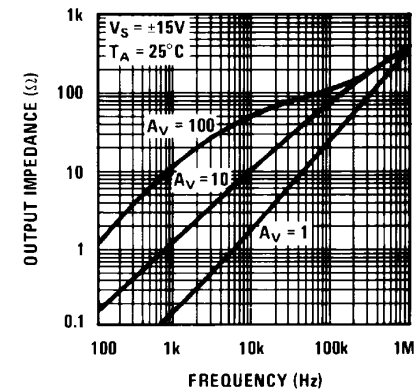
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Negative Current Limit



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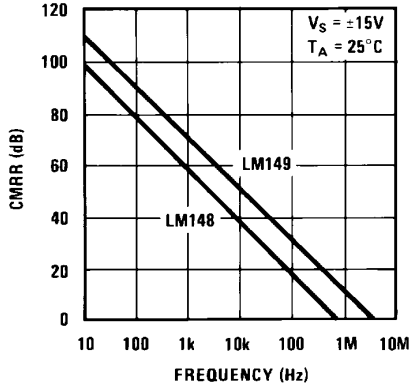
Output Impedance



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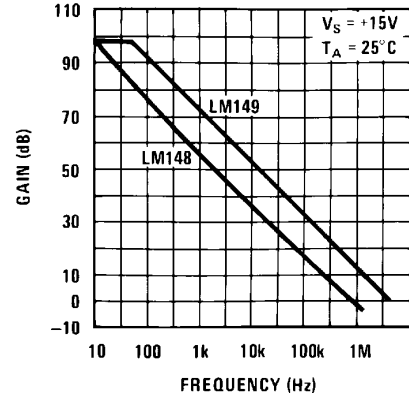
# Typical Performance Characteristics (Continued)

**Common-Mode Rejection Ratio**



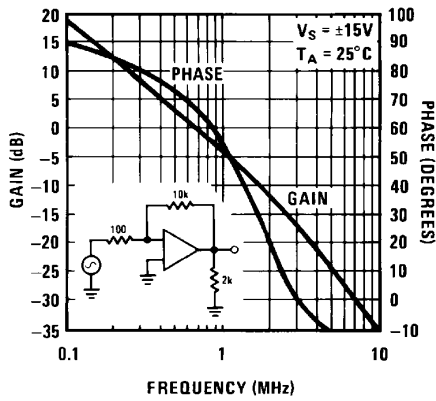
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**Open Loop Frequency Response**



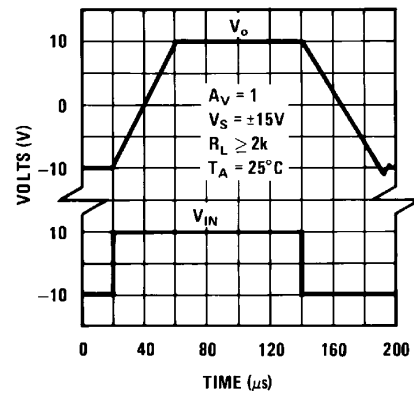
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**Bode Plot LM148**



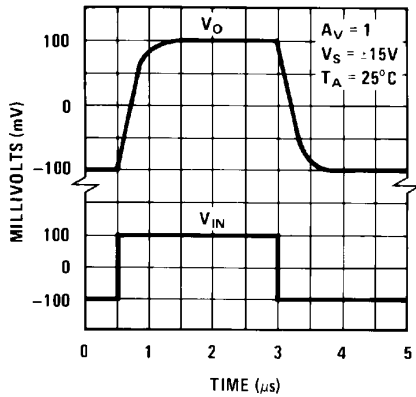
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**Large Signal Pulse Response (LM148)**



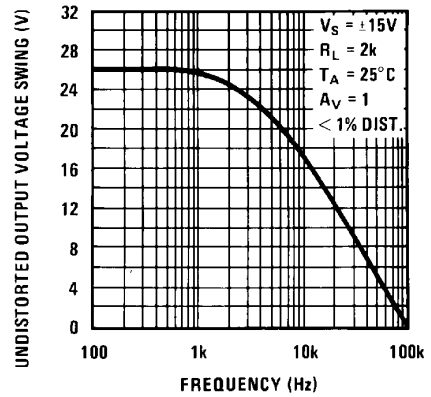
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**Small Signal Pulse Response (LM148)**



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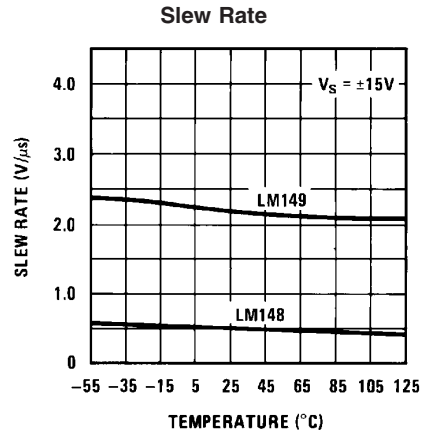
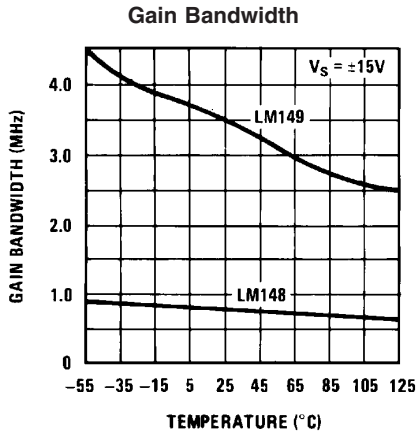
**Undistorted Output Voltage Swing**



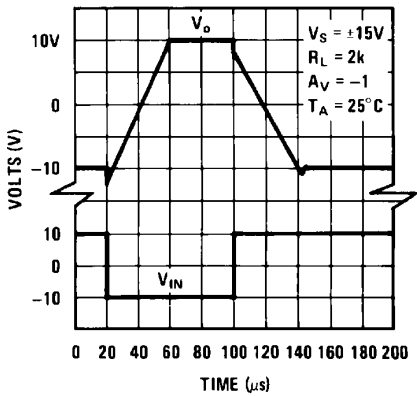
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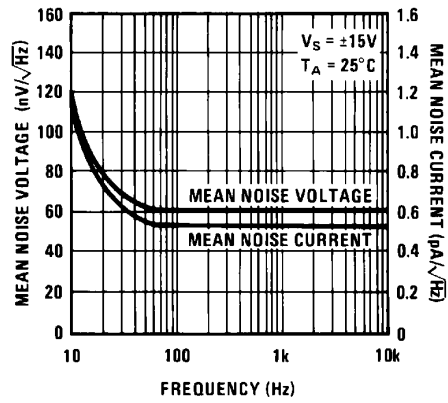
Typical Performance Characteristics (Continued)



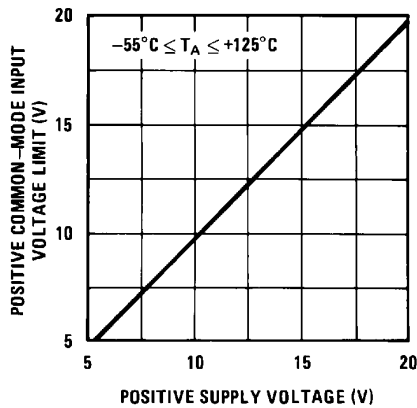
Inverting Large Signal Pulse Response (LM148)



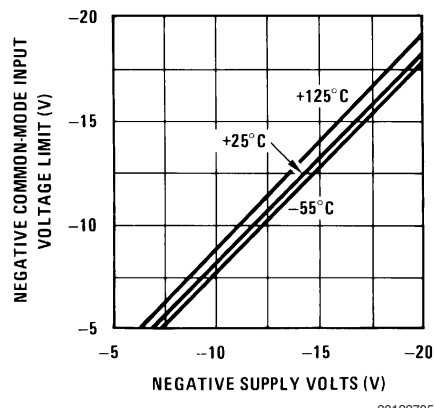
Input Noise Voltage and Noise Current



Positive Common-Mode Input Voltage Limit



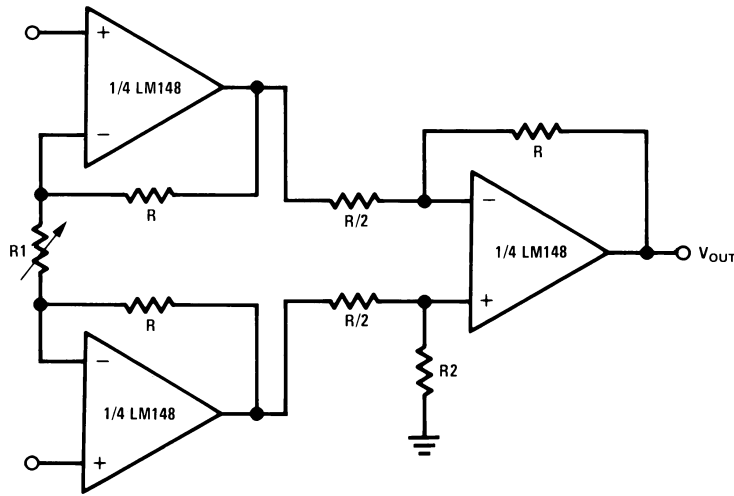
Negative Common-Mode Input Voltage Limit





# Typical Applications—LM148 (Continued)

## Low Cost Instrumentation Amplifier



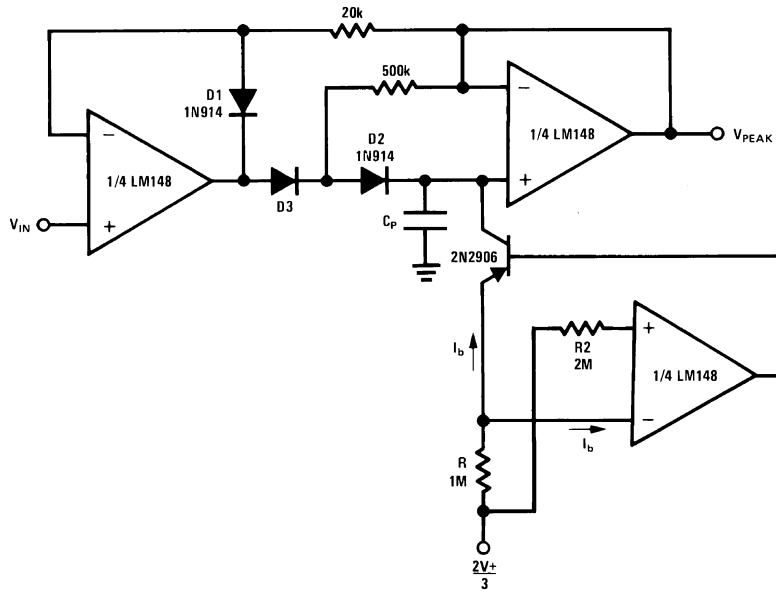
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$$V_{OUT} = 2 \left( \frac{2R}{R1} + 1 \right) \cdot V_S - 3V \leq V_{IN\ CM} \leq V_S^+ - 3V,$$

$V_S = \pm 15V$

$R = R2$ , trim  $R2$  to boost CMRR

## Low Drift Peak Detector with Bias Current Compensation

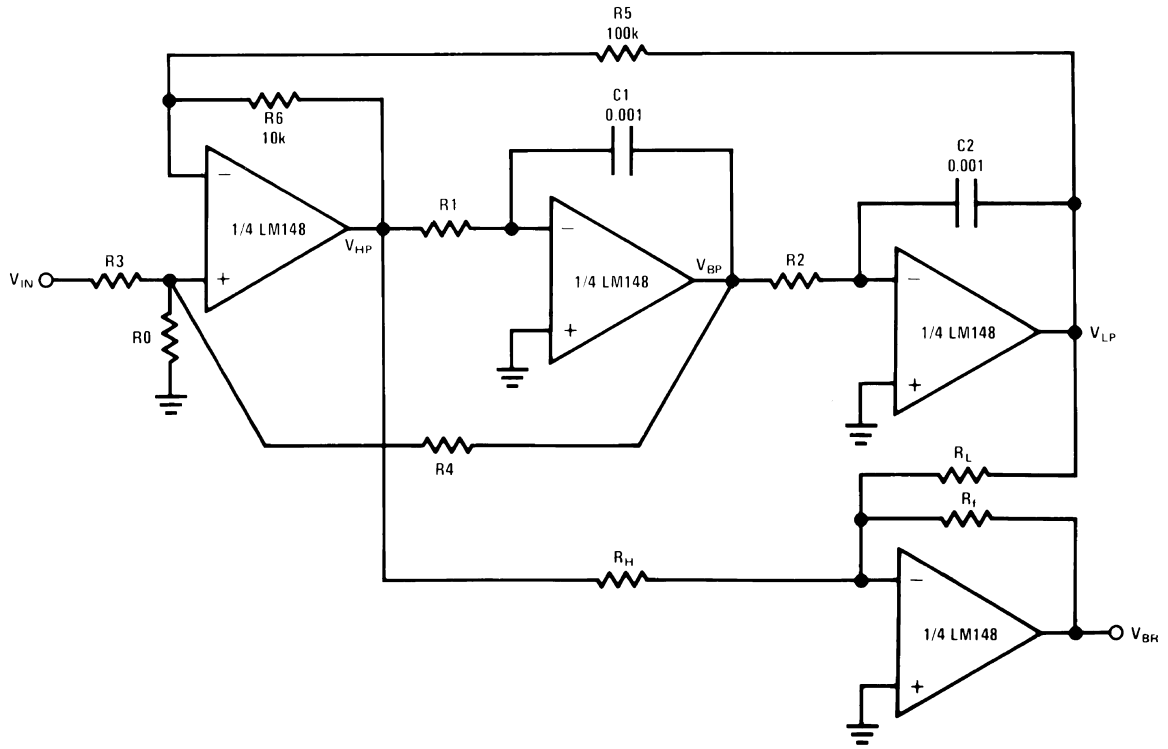


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Adjust R for minimum drift  
 D3 low leakage diode  
 D1 added to improve speed  
 $V_S = \pm 15V$

# Typical Applications—LM148 (Continued)

## Universal State-Variable Filter



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Tune Q through R0,

For predictable results:  $f_0 Q \leq 4 \times 10^4$

Use Band Pass output to tune for Q

$$\frac{V(s)}{V_{IN}(s)} = \frac{N(s)}{D(s)}, \quad D(s) = s^2 + \frac{s\omega_0}{Q} + \omega_0^2$$

$$N_{HP}(s) = s^2 H_{OHP}, \quad N_{BP}(s) = \frac{-s\omega_0 H_{OBP}}{Q}, \quad N_{LP} = \omega_0^2 H_{OLP}$$

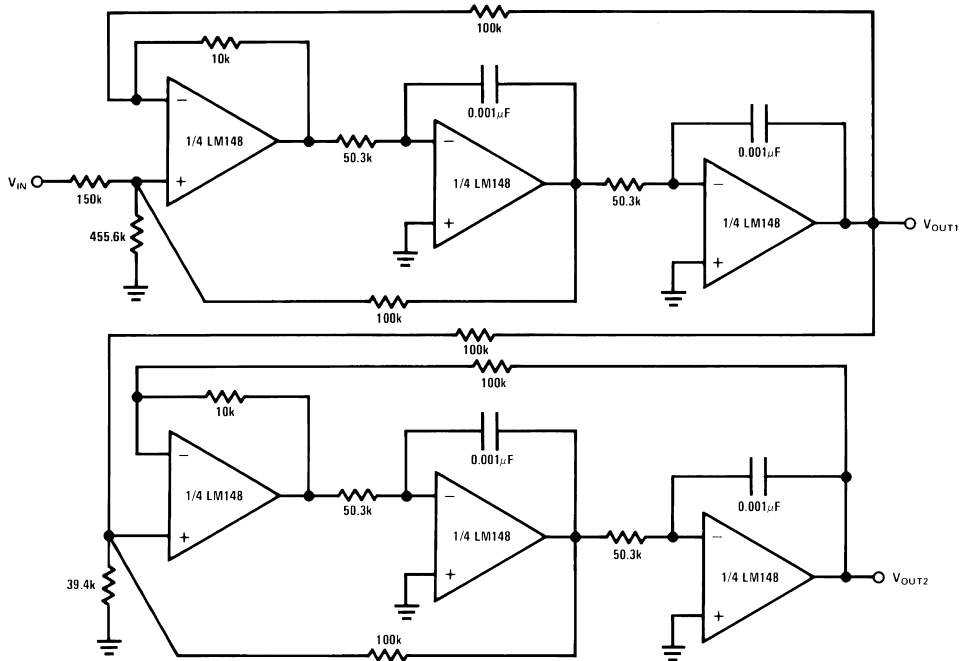
$$f_0 = \frac{1}{2\pi} \sqrt{\frac{R_6}{R_5}} \sqrt{\frac{1}{t_1 t_2}}, \quad t_i = R_i C_i, \quad Q = \left( \frac{1 + R_4/R_3 + R_4/R_0}{1 + R_6/R_5} \right) \left( \frac{R_6 t_1}{R_5 t_2} \right)^{1/2}$$

$$f_{NOTCH} = \frac{1}{2\pi} \left( \frac{R_H}{R_L t_1 t_2} \right)^{1/2}, \quad H_{OHP} = \frac{1 + R_6/R_5}{1 + R_3/R_0 + R_3/R_4}, \quad H_{OBP} = \frac{1 + R_4/R_3 + R_4/R_0}{1 + R_3/R_0 + R_3/R_4}$$

$$H_{OLP} = \frac{1 + R_5/R_6}{1 + R_3/R_0 + R_3/R_4}$$

# Typical Applications—LM148 (Continued)

## A 1 kHz 4 Pole Butterworth



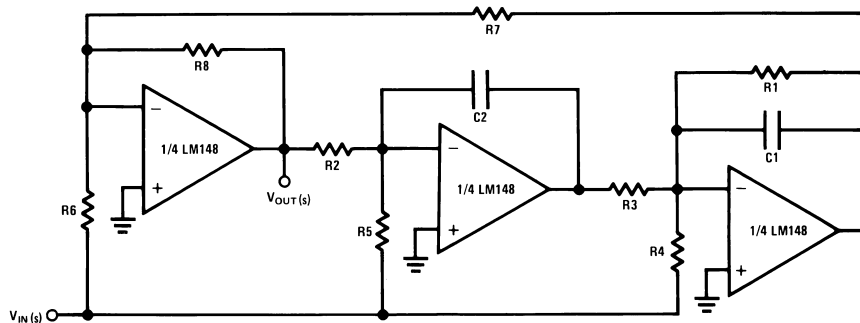
20122712

Use general equations, and tune each section separately

$Q_{1stSECTION} = 0.541$ ,  $Q_{2ndSECTION} = 1.306$

The response should have 0 dB peaking

## A 3 Amplifier Bi-Quad Notch Filter



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$$Q = \sqrt{\frac{R8}{R7}} \times \frac{R1C1}{\sqrt{R3C2R2C1}}, \quad f_o = \frac{1}{2\pi} \sqrt{\frac{R8}{R7}} \times \frac{1}{\sqrt{R2R3C1C2}}, \quad f_{NOTCH} = \frac{1}{2\pi} \sqrt{\frac{R6}{R3R5R7C1C2}}$$

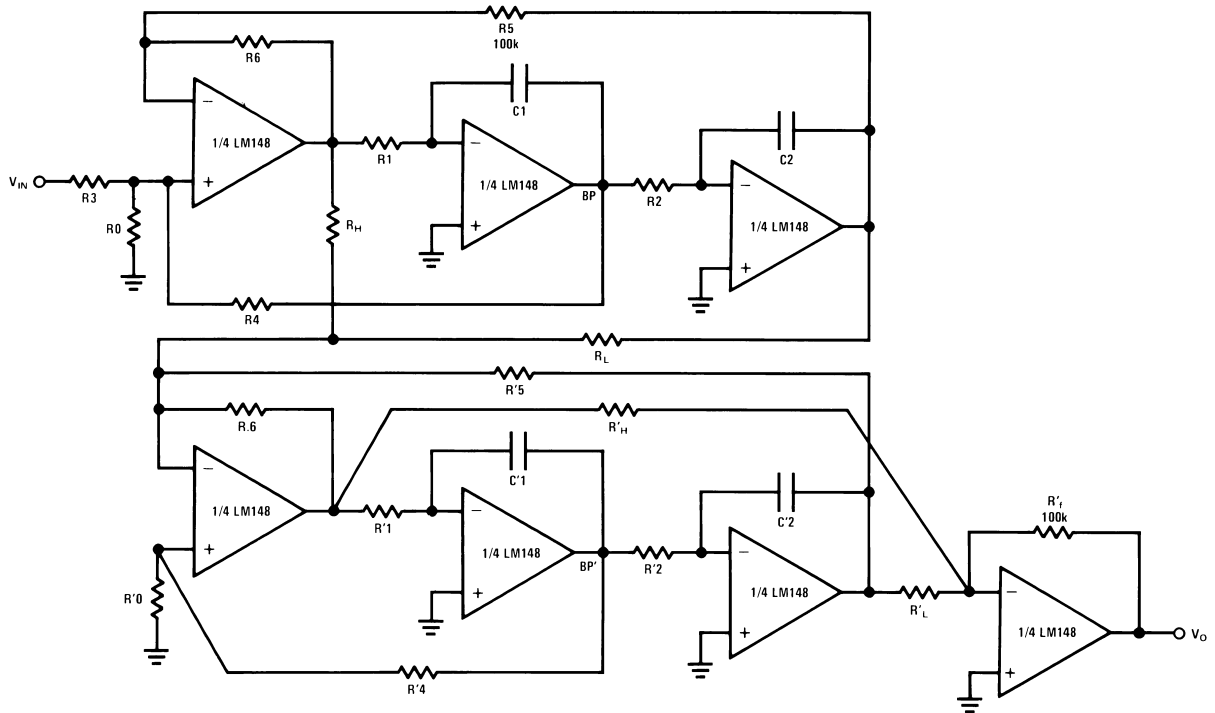
$$\text{Necessary condition for notch: } \frac{1}{R6} = \frac{R1}{R4R7}$$

Ex:  $f_{NOTCH} = 3 \text{ kHz}$ ,  $Q = 5$ ,  $R1 = 270k$ ,  $R2 = R3 = 20k$ ,  $R4 = 27k$ ,  $R5 = 20k$ ,  $R6 = R8 = 10k$ ,  $R7 = 100k$ ,  $C1 = C2 = 0.001 \mu\text{F}$

Better noise performance than the state-space approach.

# Typical Applications—LM148 (Continued)

## A 4th Order 1 kHz Elliptic Filter (4 Poles, 4 Zeros)



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$$R1C1 = R2C2 = t$$

$$R'1C'1 = R'2C'2 = t'$$

$f_C = 1 \text{ kHz}$ ,  $f_S = 2 \text{ kHz}$ ,  $f_p = 0.543$ ,  $f_z = 2.14$ ,  $Q = 0.841$ ,  $f'_p = 0.987$ ,  $f'_z = 4.92$ ,  $Q' = 4.403$ , normalized to ripple BW

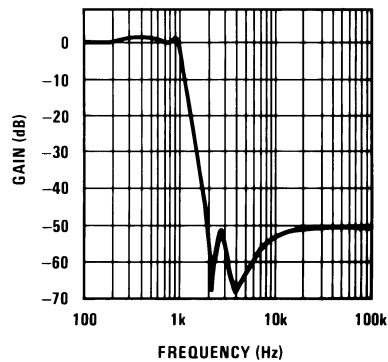
$$f = \frac{1}{2\pi R1C1} \times \sqrt{K}, K = \frac{R4R5}{R3} \left( \frac{1}{r_{DS}} + \frac{1}{R4} + \frac{1}{R5} \right), r_{DS} \approx \frac{R_{ON}}{\left( 1 - \frac{V_{GS}}{V_P} \right)^{1/2}}$$

Use the BP outputs to tune Q, Q', tune the 2 sections separately

$R1 = R2 = 92.6k$ ,  $R3 = R4 = R5 = 100k$ ,  $R6 = 10k$ ,  $R0 = 107.8k$ ,  $R_L = 100k$ ,  $R_H = 155.1k$ ,

$R'1 = R'2 = 50.9k$ ,  $R'4 = R'5 = 100k$ ,  $R'6 = 10k$ ,  $R'0 = 5.78k$ ,  $R'_L = 100k$ ,  $R'_H = 248.12k$ ,  $R'_f = 100k$ . All capacitors are 0.001  $\mu F$ .

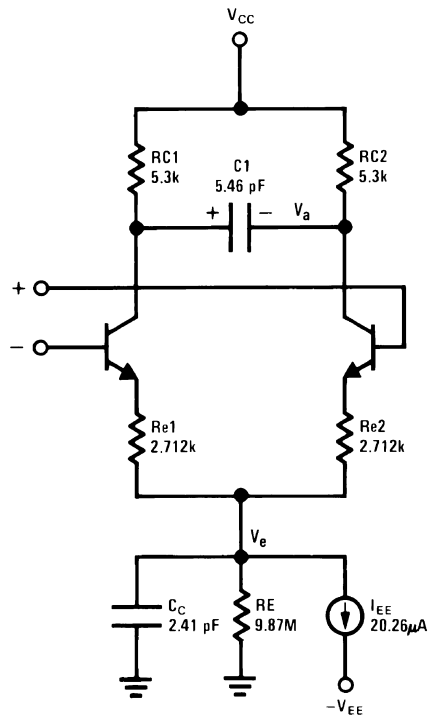
Lowpass Response



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# Typical Simulation

LM148, LM741 Macromodel for Computer Simulation

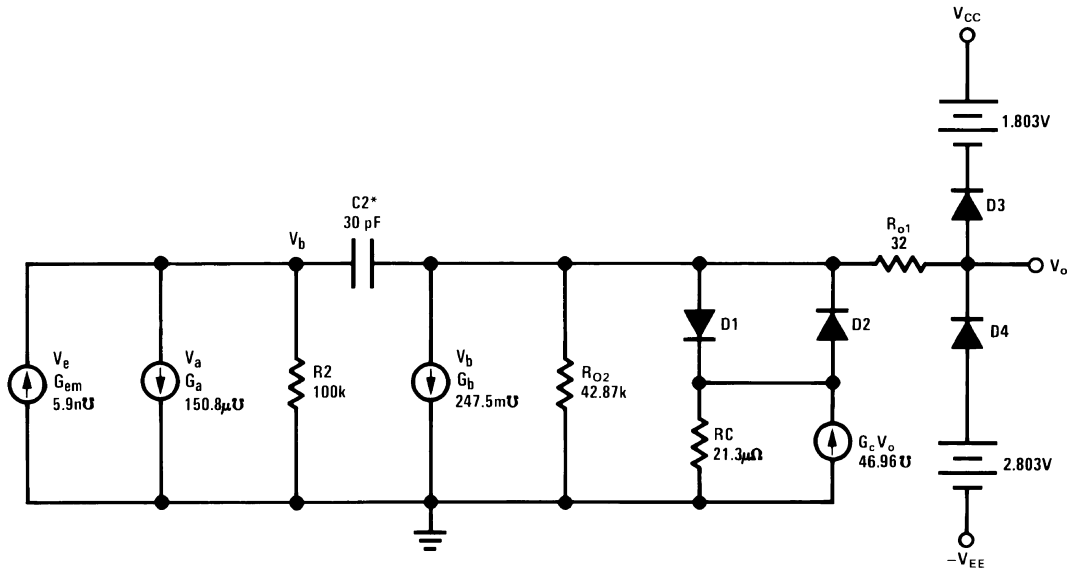


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For more details, see IEEE Journal of Solid-State Circuits, Vol. SC-9, No. 6, December 1974

**Note 8:**  $\omega_1 = 112I_S = 8 \times 10^{-16}$

**Note 9:**  $\omega_2 = 144^*C2 = 6 \text{ pF}$  for LM149



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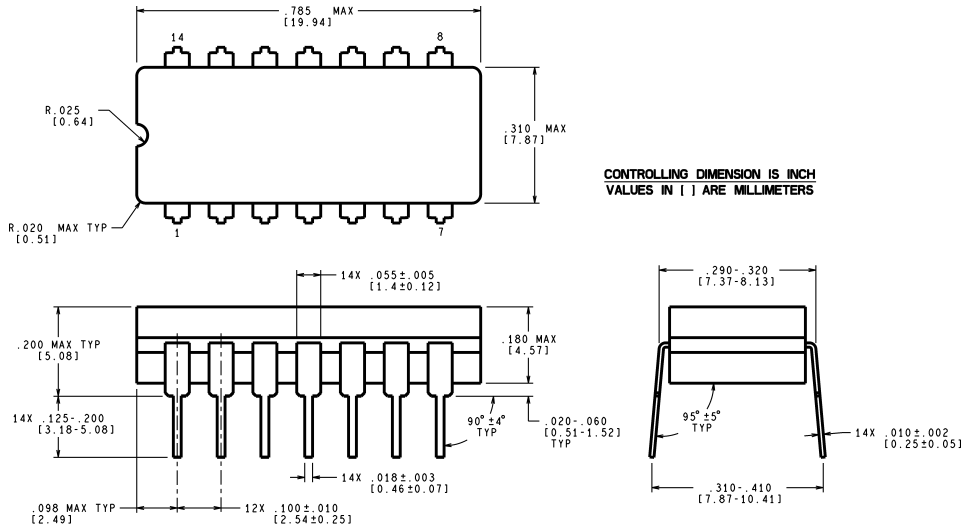
## Revision History Section

| Date Released | Revision | Section                       | Originator | Changes  |
|---------------|----------|-------------------------------|------------|--|
| 02/15/05      | A        | New Release, Corporate format | L. Lytle   | 1 MDS data sheet converted into one Corp. data sheet format. MJLM148-X, Rev. 0C1. MDS data sheet will be archived. |



**Physical Dimensions** inches (millimeters)

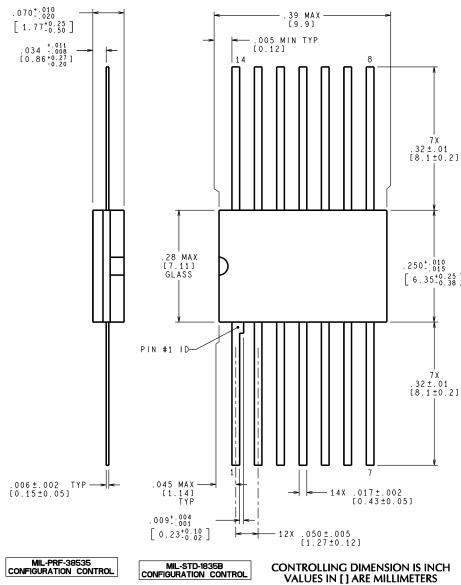
unless otherwise noted



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VALUES IN [ ] ARE MILLIMETERS

J14A (Rev J)

**Ceramic Dual-In-Line Package (J)  
NS Package Number J14A**

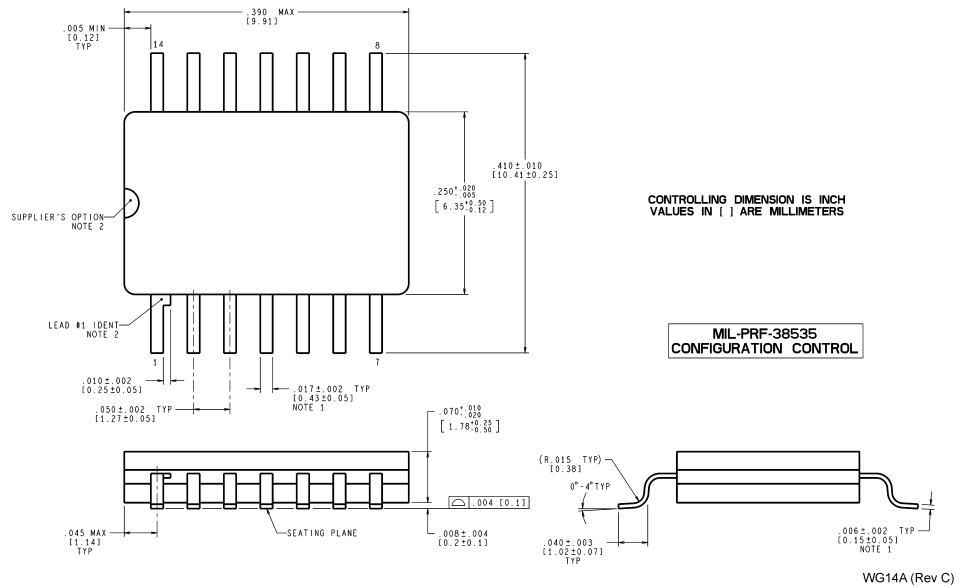


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W14B (Rev P)

**Ceramic Flatpack (W)  
NS Package Number W14B**

**Physical Dimensions** inches (millimeters) unless otherwise noted (Continued)



**Ceramic SOIC (WG)  
NS Package Number WG14A**

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